

## **PERSON SPECIFICATION**

Ref: A2773

Criteria	Essential/ Desirable	Application Form/ Supporting Statements/ Interview*
A good understanding of basic semiconductor physics concepts, particularly with respect to narrow bandgap III-V Arsenide and Antimonide materials and their potential for use in infrared optoelectronics.	Essential	Supporting Statements/Interview
Specific understanding of the theory behind resonant cavity enhanced detectors and InAs/InAsSb strained layer superlattices.	Essential	Supporting Statements/Interview
First-hand knowledge and experience in the growth of antimonide alloys and infrared detectors by MBE.	Essential	Supporting Statements/Interview
First-hand knowledge and experience in the cleanroom based fabrication of superlattice detectors.	Essential	Supporting Statements/Interview
Experience in the optoelectronic characterisation of infrared detectors.	Essential	Supporting Statements/Interview
PhD in Physics or a similar subject.	Essential	Application Form
Be an effective communicator with good inter-personal skills and a strong command of English.	Essential	Application Form / Interview
The ability to co-operate with others and work as part of a team, including with industrial partners.	Essential	Supporting Statements
Be enthusiastic, well-organised and capable of working independently to drive project progress.	Desirable	Supporting Statements

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- Application Form assessed against the application form, curriculum vitae and letter of support. Applicants will not be asked to make a specific supporting statement. Normally used to evaluate factual evidence eg award of a PhD. Will be "scored" as part of the shortlisting process.
- **Supporting Statements** applicant are asked to provide a statement to demonstrate how they meet the criteria. The response will be "scored" as part of the shortlisting process.
- **Interview** assessed during the interview process by either competency based interview questions, tests, presentation etc.